

# High Power Infrared Emitter (850 nm)

## Version 1.5

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### SFH 4253



#### Features:

- High Power Infrared LED
- Short switching time
- The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.

#### Applications

- Infrared Illumination for cameras
- IR data transmission
- Sensor technology

#### Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

#### Ordering Information

| Type:      | Radiant Intensity                                              | Ordering Code |
|------------|----------------------------------------------------------------|---------------|
|            | $I_e$ [mW/sr]<br>$I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$ |               |
| SFH 4253   | 13 ( $\geq 6.3$ )                                              | Q65110A6657   |
| SFH 4253-R | 10 ... 20                                                      | Q65111A9684   |

*Note:* Measured at a solid angle of  $\Omega = 0.01 \text{ sr}$

**Maximum Ratings** ( $T_A = 25\text{ °C}$ )

| Parameter                                                              | Symbol            | Values      | Unit  |
|------------------------------------------------------------------------|-------------------|-------------|-------|
| Operation and storage temperature range                                | $T_{op}; T_{stg}$ | -40 ... 100 | °C    |
| Reverse voltage                                                        | $V_R$             | 5           | V     |
| Forward current                                                        | $I_F$             | 70          | mA    |
| Surge current<br>( $t_p = 100\text{ }\mu\text{s}$ , $D = 0$ )          | $I_{FSM}$         | 0.7         | A     |
| Power consumption                                                      | $P_{tot}$         | 140         | mW    |
| ESD withstand voltage<br>(acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)      | $V_{ESD}$         | 2           | kV    |
| Thermal resistance junction - ambient <sup>1) page 12</sup>            | $R_{thJA}$        | 500         | K / W |
| Thermal resistance junction - soldering point<br><sup>2) page 12</sup> | $R_{thJS}$        | 280         | K / W |

**Characteristics** ( $T_A = 25\text{ °C}$ )

| Parameter                                                                                                         |             | Symbol               | Values                             | Unit          |
|-------------------------------------------------------------------------------------------------------------------|-------------|----------------------|------------------------------------|---------------|
| Peak wavelength<br>( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )                                                | (typ)       | $\lambda_{peak}$     | 860                                | nm            |
| Centroid wavelength<br>( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )                                            | (typ)       | $\lambda_{centroid}$ | 850                                | nm            |
| Spectral bandwidth at 50% of $I_{max}$<br>( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )                         | (typ)       | $\Delta\lambda$      | 30                                 | nm            |
| Half angle                                                                                                        | (typ)       | $\varphi$            | $\pm 60$                           | °             |
| Dimensions of active chip area                                                                                    | (typ)       | L x W                | 0.2 x 0.2                          | mm x mm       |
| Rise and fall time of $I_e$ ( 10% and 90% of $I_{e\max}$ )<br>( $I_F = 70\text{ mA}$ , $R_L = 50\text{ }\Omega$ ) | (typ)       | $t_r, t_f$           | 12                                 | ns            |
| Forward voltage<br>( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )                                                | (typ (max)) | $V_F$                | 1.6 ( $\leq 2$ )                   | V             |
| Forward voltage<br>( $I_F = 500\text{ mA}$ , $t_p = 100\text{ }\mu\text{s}$ )                                     | (typ (max)) | $V_F$                | 2.4 ( $\leq 3$ )                   | V             |
| Reverse current<br>( $V_R = 5\text{ V}$ )                                                                         |             | $I_R$                | not designed for reverse operation | $\mu\text{A}$ |
| Total radiant flux<br>( $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$ )                                             | (typ)       | $\Phi_e$             | 40                                 | mW            |

| Parameter                                                                                         |       | Symbol       | Values | Unit   |
|---------------------------------------------------------------------------------------------------|-------|--------------|--------|--------|
| Temperature coefficient of $I_e$ or $\Phi_e$<br>( $I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$ ) | (typ) | $TC_I$       | -0.5   | % / K  |
| Temperature coefficient of $V_F$<br>( $I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$ )             | (typ) | $TC_V$       | -0.7   | mV / K |
| Temperature coefficient of wavelength<br>( $I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$ )        | (typ) | $TC_\lambda$ | 0.3    | nm / K |

**Grouping** ( $T_A = 25^\circ\text{C}$ )

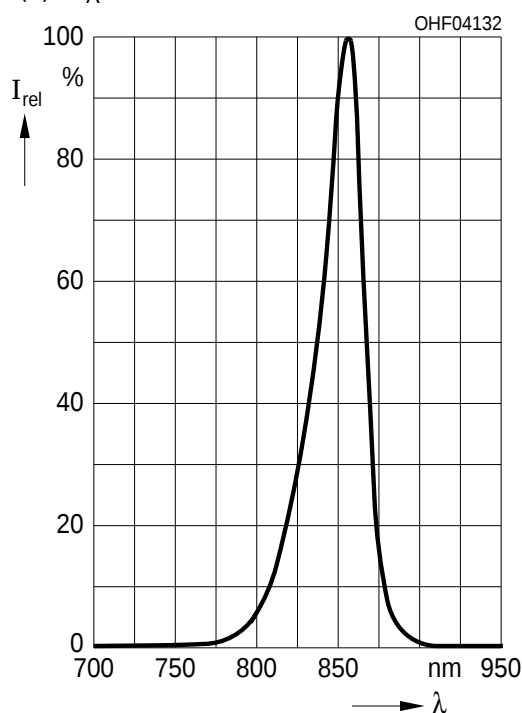
| Group      | Min Radiant Intensity<br>$I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$<br>$I_{e, \min}$ [mW / sr] | Max Radiant Intensity<br>$I_F = 70 \text{ mA}$ , $t_p = 20 \text{ ms}$<br>$I_{e, \max}$ [mW / sr] | Typ Radiant Intensity<br>$I_F = 500 \text{ mA}$ , $t_p = 25 \mu\text{s}$<br>$I_{e, \text{typ}}$ [mW / sr] |
|------------|---------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------|
| SFH 4253-Q | 6.3                                                                                               | 12.5                                                                                              | 55                                                                                                        |
| SFH 4253-R | 10                                                                                                | 20                                                                                                | 90                                                                                                        |

Note: measured at a solid angle of  $\Omega = 0.01 \text{ sr}$

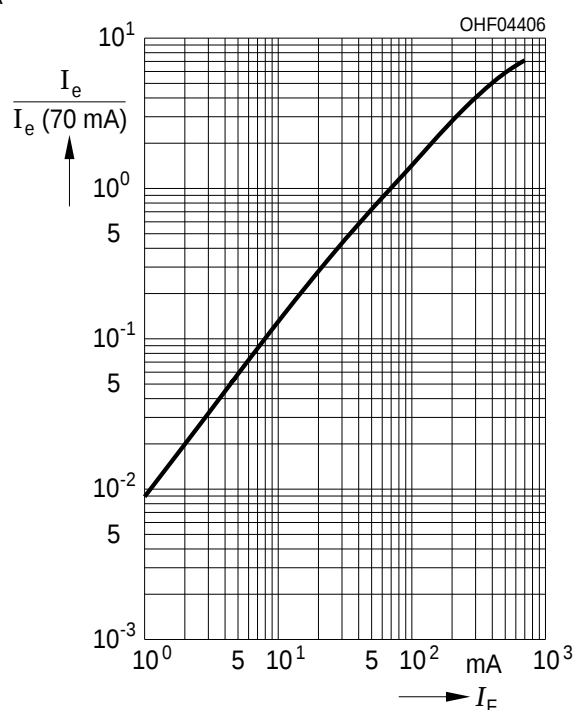
Only one group in one packing unit (variation lower 2:1).

**Relative Spectral Emission** <sup>3) page 12</sup>

$$I_{\text{rel}} = f(\lambda), T_A = 25^\circ\text{C}$$

**Radiant Intensity** <sup>3) page 12</sup>

$$I_e / I_e(70 \text{ mA}) = f(I_F), \text{ single pulse, } t_p = 25 \mu\text{s}, T_A = 25^\circ\text{C}$$

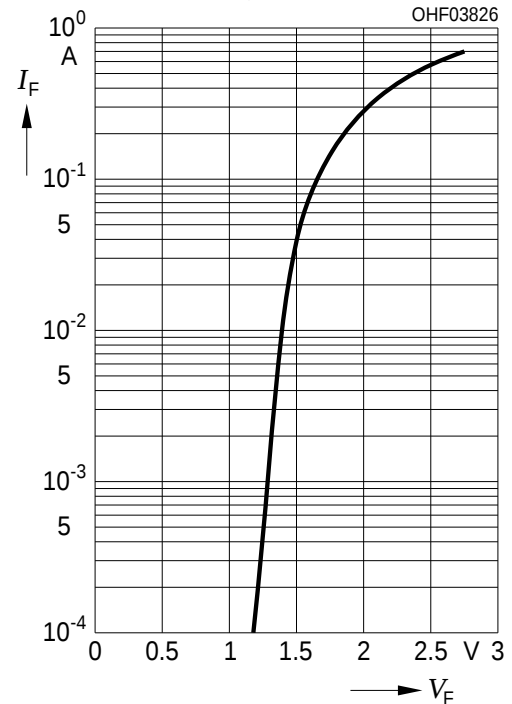


**Max. Permissible Forward Current**

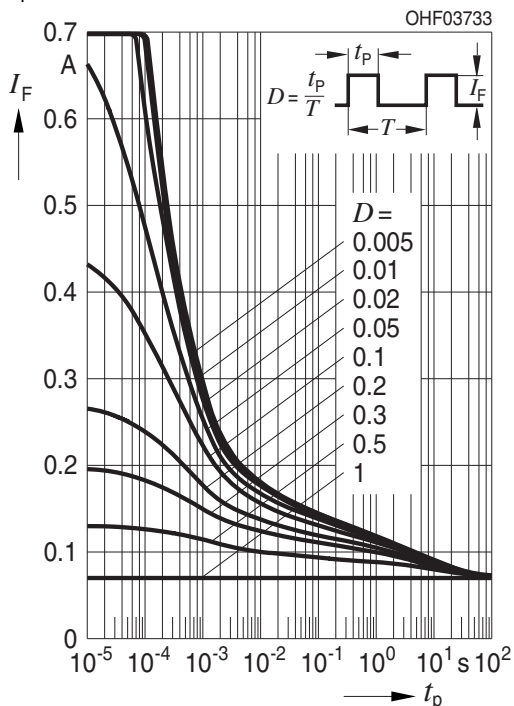
$$I_{F, \max} = f(T_A), R_{thJA} = 500 \text{ K / W}$$

**Forward Current** <sup>3) page 12</sup>

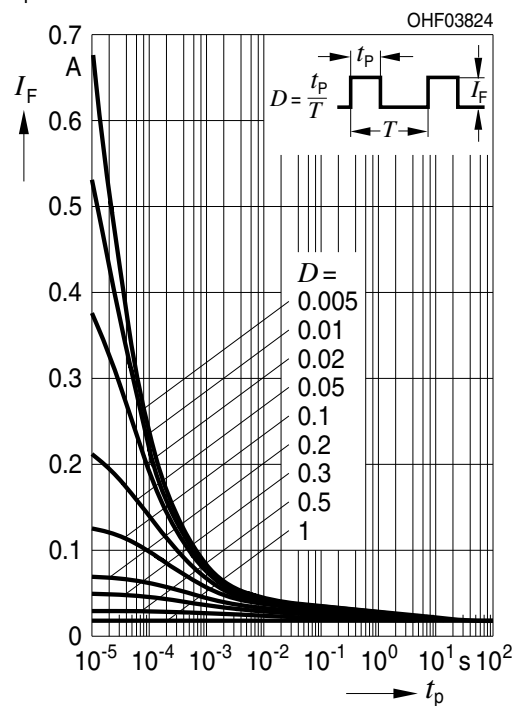
$$I_F = f(V_F), \text{ single pulse, } t_p = 100 \mu\text{s}, T_A = 25^\circ\text{C}$$

**Permissible Pulse Handling Capability**

$$I_F = f(t_p), T_A = 25^\circ\text{C}, \text{ duty cycle } D = \text{parameter}$$

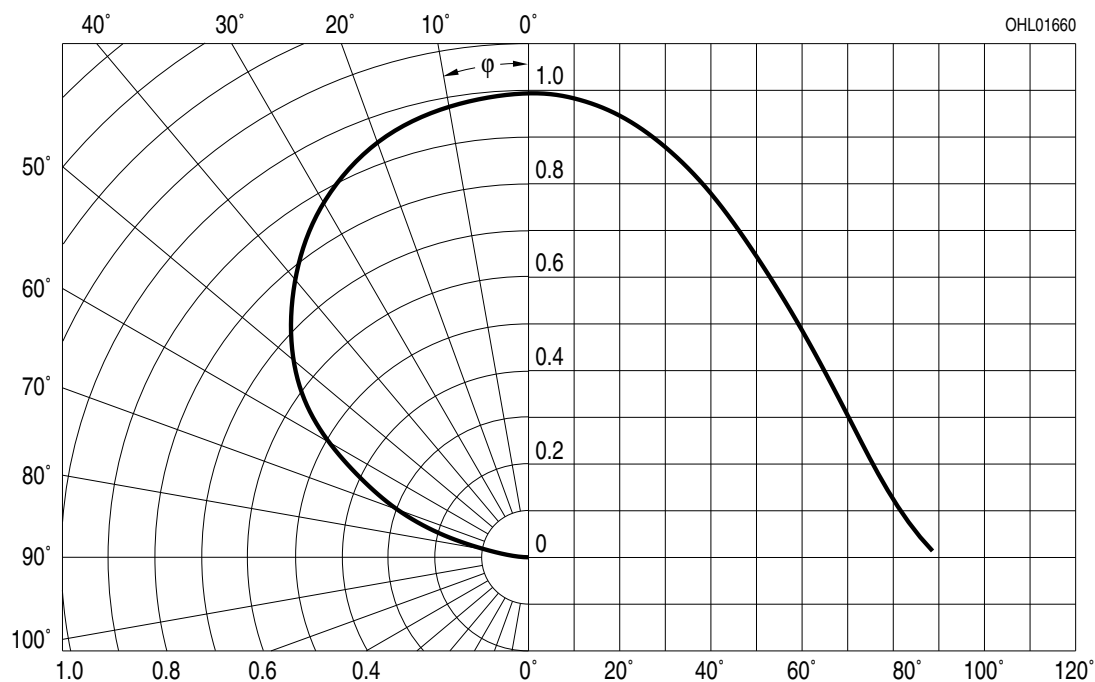
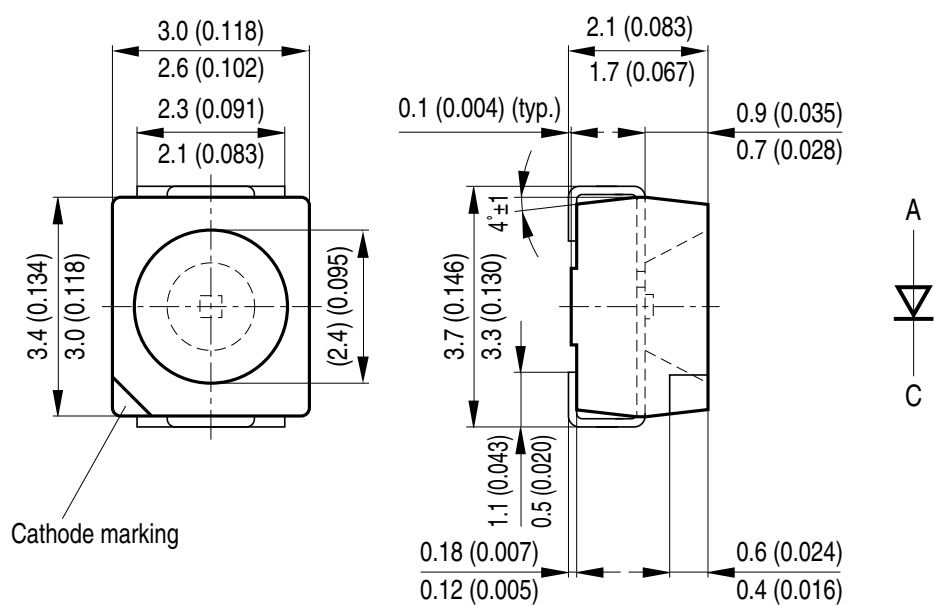
**Permissible Pulse Handling Capability**

$$I_F = f(t_p), T_A = 85^\circ\text{C}, \text{ duty cycle } D = \text{parameter}$$



**Radiation Characteristics** <sup>3) page 12</sup>

$$I_{\text{rel}} = f(\phi), T_A = 25^\circ\text{C}$$

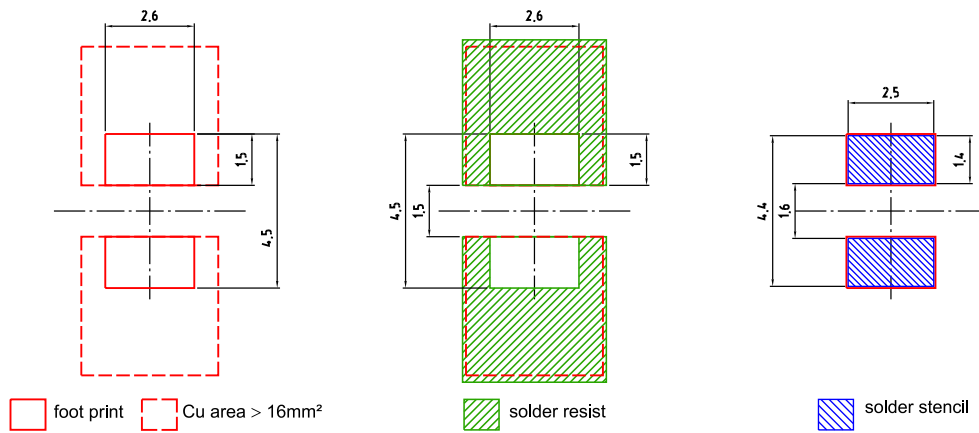
**Package Outline**

Dimensions in mm (inch).

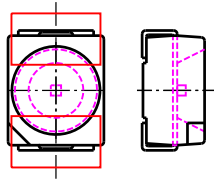
**Package**  
TOPLED

**Approximate Weight:**

35 mg

**Recommended Solder Pad**

Component Location on Pad

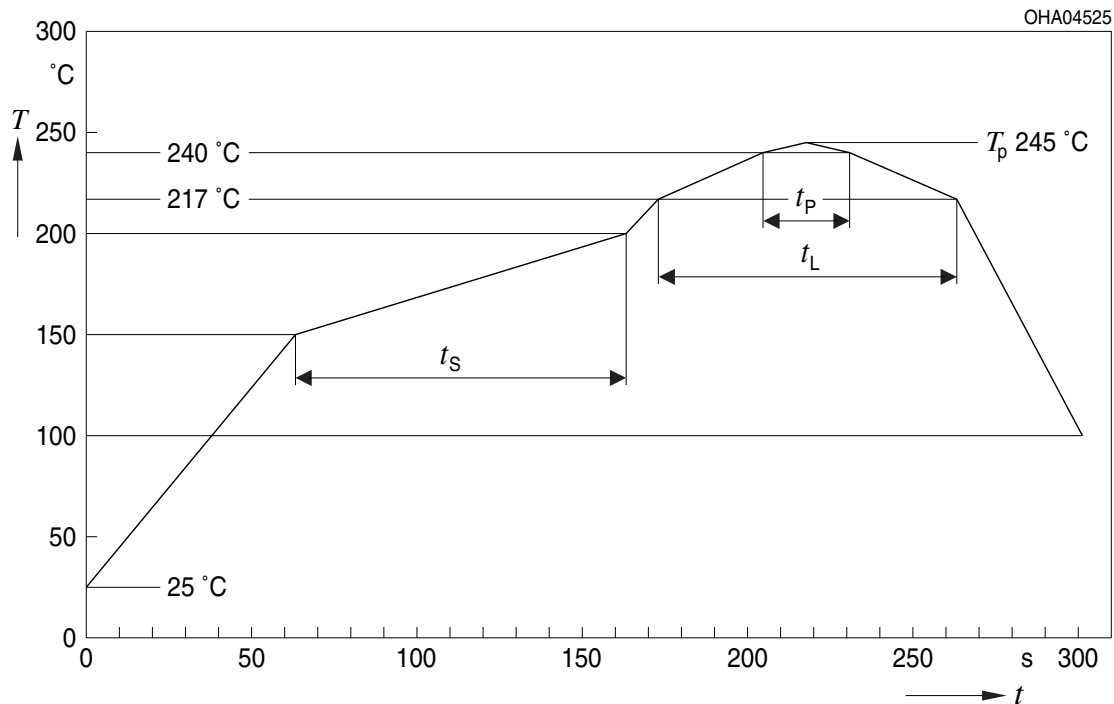


Dimensions in mm.

E062.3010.01 -02

## Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020D.01



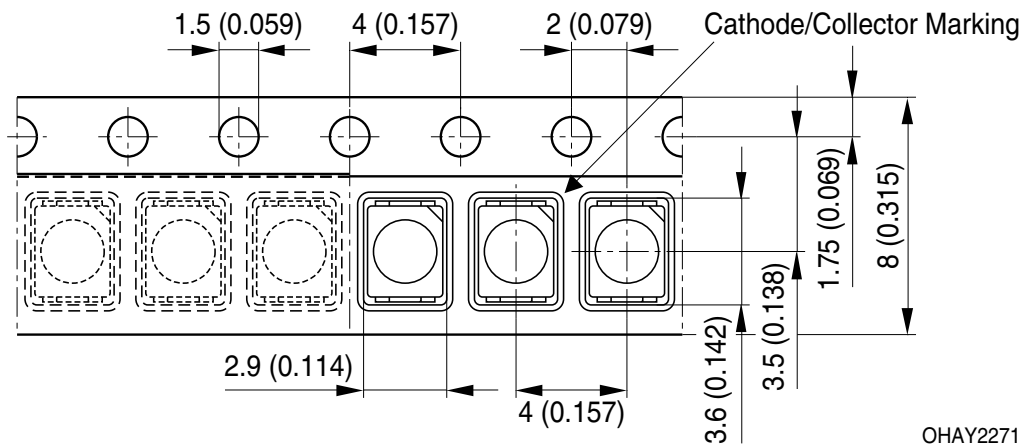
OHA04612

| Profile Feature<br>Profil-Charakteristik                                 | Symbol<br>Symbol | Pb-Free (SnAgCu) Assembly |                |         | Unit<br>Einheit    |
|--------------------------------------------------------------------------|------------------|---------------------------|----------------|---------|--------------------|
|                                                                          |                  | Minimum                   | Recommendation | Maximum |                    |
| Ramp-up rate to preheat*)<br>25 °C to 150 °C                             |                  |                           | 2              | 3       | K/s                |
| Time $t_S$<br>$T_{Smin}$ to $T_{Smax}$                                   | $t_S$            | 60                        | 100            | 120     | s                  |
| Ramp-up rate to peak*)<br>$T_{Smax}$ to $T_P$                            |                  |                           | 2              | 3       | K/s                |
| Liquidus temperature                                                     | $T_L$            | 217                       |                |         | $^{\circ}\text{C}$ |
| Time above liquidus temperature                                          | $t_L$            |                           | 80             | 100     | s                  |
| Peak temperature                                                         | $T_P$            |                           | 245            | 260     | $^{\circ}\text{C}$ |
| Time within 5 °C of the specified peak<br>temperature $T_P - 5\text{ K}$ | $t_P$            | 10                        | 20             | 30      | s                  |
| Ramp-down rate*<br>$T_P$ to 100 °C                                       |                  |                           | 3              | 6       | K/s                |
| Time<br>25 °C to $T_P$                                                   |                  |                           |                | 480     | s                  |

All temperatures refer to the center of the package, measured on the top of the component

\* slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range

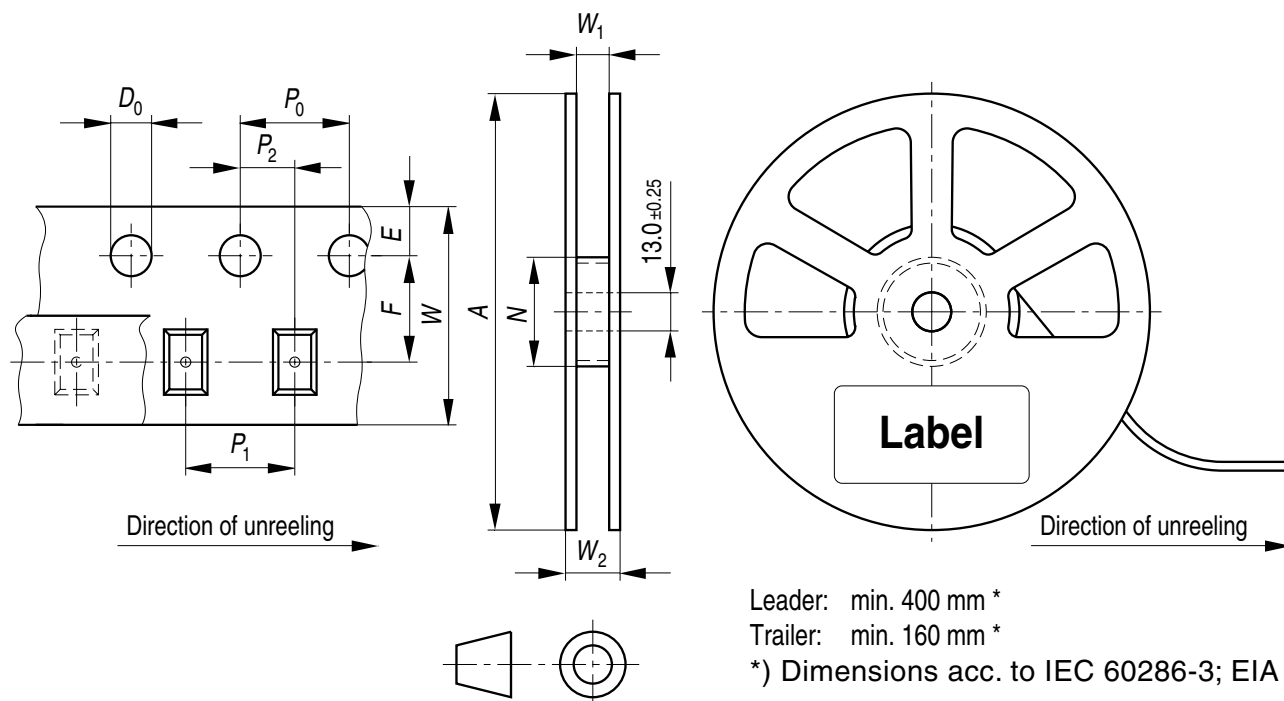
## Taping



Dimensions in mm (inch).

## Tape and Reel

8 mm tape with 2000 pcs. on  $\varnothing$  180 mm reel, 8000 pcs. on  $\varnothing$  330 mm reel



## Tape dimensions [mm]

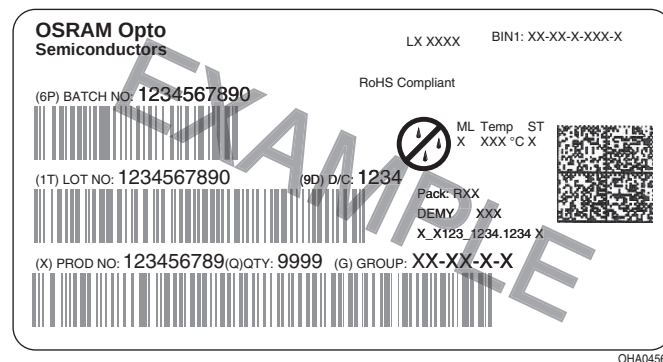
| W              | P <sub>0</sub> | P <sub>1</sub>            | P <sub>2</sub> | D <sub>0</sub> | E          | F          |
|----------------|----------------|---------------------------|----------------|----------------|------------|------------|
| 8 + 0.3 / -0.1 | 4 ± 0.1        | 2 ± 0.05<br>or<br>4 ± 0.1 | 2 ± 0.05       | 1.5 ± 0.1      | 1.75 ± 0.1 | 3.5 ± 0.05 |

## Reel dimensions [mm]

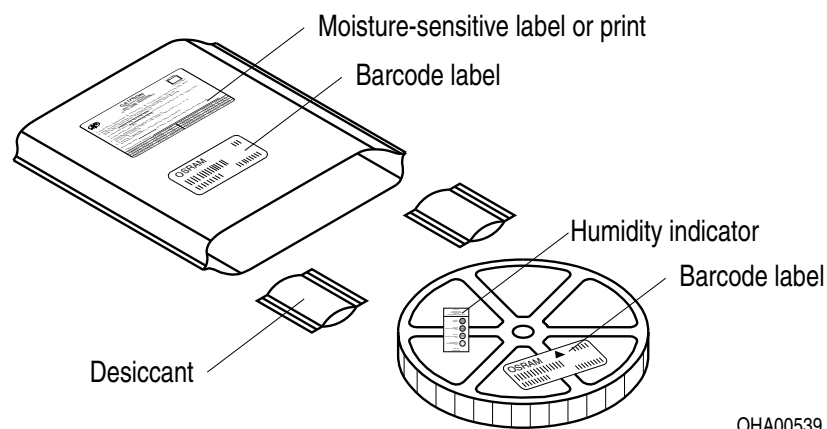
| A   | W | N <sub>min</sub> | W <sub>1</sub> | W <sub>2max</sub> |
|-----|---|------------------|----------------|-------------------|
| 180 | 8 | 60               | 8.4 + 2        | 14.4              |

| A   | W | N <sub>min</sub> | W <sub>1</sub> | W <sub>2max</sub> |
|-----|---|------------------|----------------|-------------------|
| 330 | 8 | 60               | 8.4 + 2        | 14.4              |

## Barcode-Product-Label (BPL)



## Dry Packing Process and Materials

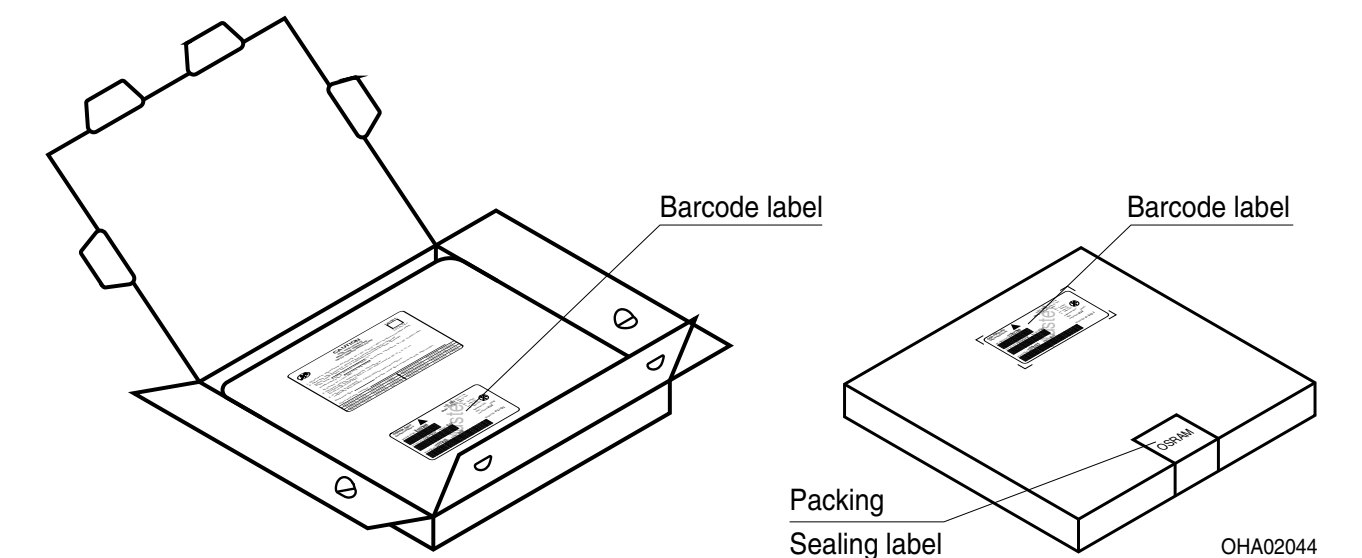


## Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative

references like JEDEC.

Transportation Packing and Materials



Dimensions of transportation box in mm

| Width   | Length  | Height |
|---------|---------|--------|
| 200 ± 5 | 195 ± 5 | 30 ± 5 |
| 352 ± 5 | 352 ± 5 | 33 ± 5 |

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

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\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

**Glossary**

- <sup>1)</sup> **Thermal resistance:** junction -ambient, mounted on PC-board (FR4), padsize 16 mm<sup>2</sup> each
- <sup>2)</sup> **Thermal resistance:** junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- <sup>3)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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